

Features

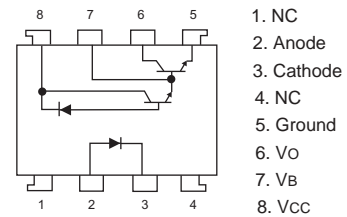
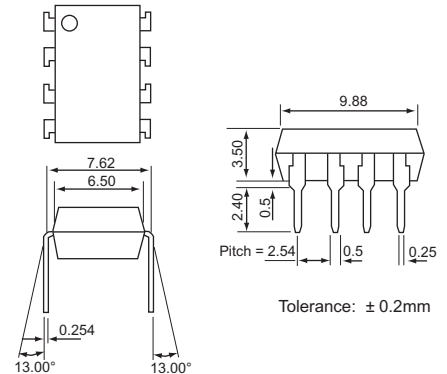
1. High current transfer ratio.
(CTR: MIN. 300% at $I_F = 1.6\text{mA}$)
2. High speed response.
(t_{PHL} : TYP. 0.2 μs at $R_L = 2.2\text{kohms}$)
3. Instantaneous common mode rejection voltage. (CM_H : TYP. 500V/ μs)
4. TTL compatible output. Overseas standard model.
5. Available package types: DIP(shown)/ SMD/ H (Page: 148).

Part Numbering System: Page 2. **Part Marking System:** Page 3.

Applications

1. Interfaces for computer peripherals.
2. Electronic calculators, measuring instruments, control equipment.
3. Telephone sets.
4. Signal transmission between circuits of different potentials and impedances.

Outside Dimension: Unit (mm)



1. NC
2. Anode
3. Cathode
4. NC
5. Ground
6. Vo
7. Vb
8. Vcc

Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	20	mA
	Peak transient forward current ¹	I_{FM}	1	A
	Reverse voltage	V_R	5	V
	Power dissipation	P_D	35	mW
Output	Supply voltage	V_{CC}	-0.5 to +7	V
	Output voltage	V_O	-0.5 to +7	V
	Emitter-base reverse with-stand voltage (PIn 5 to 7)	V_{EBO}	0.5	mA
	Average output current ²	I_o	60	mA
	Power dissipation	P_o	100	mW
	Isolation voltage ³	V_{iso}	2500	V_{rms}
	Operating temperature	T_{opr}	0 to +70	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +125	$^\circ\text{C}$	
	Soldering temperature 10 seconds	T_{sol}	260	$^\circ\text{C}$

1. Pulse width $\leq 1\mu\text{s}$, 300 pulse/sec. Peak forward current, 40mA, 50% duty cycle, Pulse width 1mS.
2. Decreases at the rate of 0.7mA/ $^\circ\text{C}$ if the external temperature is more than 25 $^\circ\text{C}$ or more.
3. 40 to 60% RH, AC for 1 minute.

Electro-optical Characteristics

(Ta = 0 to 70°C unless otherwise specified)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Current transfer ratio ¹	CTR	I _F = 1.6mA, V _O = 0.4V, V _{CC} = 4.5V	300	1600	-	%
Logic (0) output voltage	V _{OL}	I _F = 1.6mA, I _O = 4.8mA, V _{CC} = 4.5V	-	0.1	0.4	V
Logic (1) output current	I _{OH}	I _F = 0, V _{CC} = V _O = 7V	-	0.1	250	µA
Logic (0) supply current	I _{CC}	I _F = 1.6mA, V _{CC} = 5V, V _O = open	-	0.5	-	mA
Logic (1) supply current	I _{CC}	I _F = 0, V _{CC} = 5V, V _O = open	-	10	-	nA
Input forward voltage	V _F	Ta = 25°C, I _F = 1.6mA	-	1.5	1.7	V
Input forward voltage temperature coefficient	ΔV _F / ΔTa	I _F = 1.6mA	-	-1.9	-	mV/°C
Input reverse voltage	BV _R	Ta = 25°C, I _R = 10µA	5.0	-	-	V
Input capacitance	C _{IN}	V _F = 0, f = 1MHz	-	60	-	pF
Leak current (input-output) ²	I _{I-O}	V _{I-O} = 3kV DC, 45%RH, t = 5s, Ta = 25°C	-	-	1.0	µA
Isolation resistance (input-output) ²	R _{I-O}	V _{I-O} = 500V DC	-	10 ¹²	-	Ω
Capacitance (input-output) ²	C _{I-O}	f = 1MHz	-	0.6	-	pF

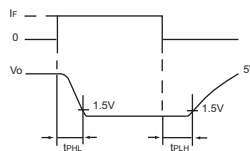
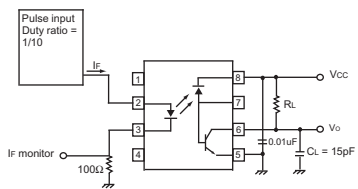
- Current transfer ratio is the ratio of input current and output current expressed in %.
- Measured as 2-pin element (Short 1, 2, 3, 4 and 5, 6, 7, 8).

Switching Characteristics

(Ta = 25°C, V_{CC} = 5V, I_F = 16mA)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Propagation delay time ³ Output (1) → (0)	t _{PHL}	R _L = 2.2kohms, I _F = 1.6mA	-	2	10	µs
Propagation delay time ³ Output (0) → (1)	t _{PLH}	R _L = 2.2kohms, I _F = 1.6mA	-	7	35	µs
Instantaneous common mode rejection voltage ^{1, 2, 4} Output (1)	CM _H	I _F = 0, V _{CM} = 10V _{p-p} , R _L = 2.2kohms	-	500	-	V/µs
Instantaneous common mode rejection voltage ^{1, 2, 4} Output (0)	CM _L	I _F = 1.6mA, V _{CM} = 10V _{p-p} , R _L = 2.2kohms	-	-500	-	V/µs

- Instantaneous common mode rejection voltage "output(1)" represents a common voltage variation that can hold the output above(1) level (V_O > 2.0V).
- Instantaneous common mode rejection voltage "output (0)" represents a common voltage variation that can hold the output above (0) level (V_O < 0.8V).
- Tset Circuit Propagation Delay Time



- Tset Circuit for Instantaneous Common Mode Rejection Voltage

